

INFORMATION DISCLOSURE **STATEMENT** FORM PTO-1449

Title: SYNCHRONOUS FLASH MEMORY

Sheet 1 of 1

		U.S.	Patent References]
Examiner Initials	Patent No.	Issue Date	Name	Filing Date	eΩ	
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BUP	EP	0 929 075	Mitsubishi Denki Kabushiki Kaisha	07/14/99		

Other References				
Examiner Initials	Author, Title, Date, Pages, etc.			
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RSP	Micron, "16 Mb: x16 SDRAM" Synchronous DRAM, www.micron.com, copyright 1999 Micron Technology, Inc., pp. 1-51			

Examiner Signature	PEIKAR'	Date Considered	12	114/03	
*Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP 600. Draw line through citation if not					